60V N-Channel Enhancement Mode MOSFET

Description

The PECN6020SR uses Sh eld Gate Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g. This device is ideal for high-frequency switching and synchronous rectification.

General Features

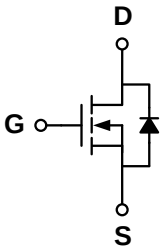
- V_{DS} =60V I_D =20A
  $R_{DS(ON)}$(Typ.)=2.8mΩ @V_{GS}=10V
  $R_{DS(ON)}$(Typ.)=4.1mΩ @V_{GS}=4.5V
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- 100% UIS tested

100% UIS TESTED!
100% ΔVds TESTED!

Application

- Synchronus Rectification in DC/DC and AC/DC Converters
- Industrial and Motor Drive applications

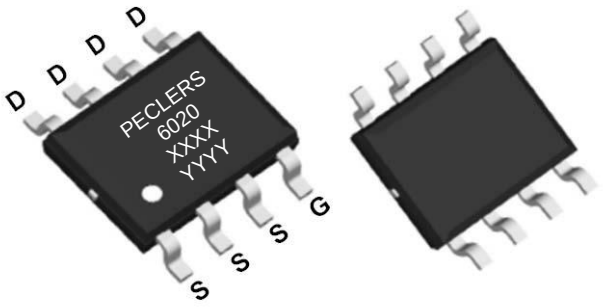
Schematic diagram



Marking and pin assignment

SOP-8

Top View Bottom View



XXXX—Date Code
YYYY—Quality Code.

RoHS HF Pb

Ordering Information

Part Number	Storage Temperature	Package	Devices Per Reel
PECN6020SR	-55°C to +150°C	SOP-8	4000

Absolute Maximum Ratings (TA=25℃ unless otherwise noted)

parameter		symbol	limit	unit
Drain-source voltage		V_{DS}	60	V
Gate-source voltage		V_{GS}	±20	V
Continuous Drain Current	TC=25°C	I_D	20	A
	TC=70°C		16	
Pulsed Drain Current		I_{DP}	80	A
Avalanche energy(T_j=25℃ ,V_{DD}=30V,V_G=10V,L=0.5mH,Rg=25Ω)		E_{AS}	320	mJ
Power Dissipation	TC=25°C	P_D	3	W
	TC=70°C		2.1	
Operating junction Temperature range		Tj	-55—150	℃

Electrical Characteristics (TA=25℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	BV_{DSS}	V_{GS}=0V, I_D=250μA	60	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS}=60V, V_{GS}=0V	-	-	1	μA
		T_J=85°C	-	-	5	
Gate Leakage Current	I_{GSS}	V_{DS}=0V, V_{GS}=±20V	-	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	1.0	1.48	2.0	V
Drain-source on-state resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=20A	-	2.8	4	mΩ
		V_{GS}=4.5V, I_D=12A		4.1	6	
Forward Transconductance	g_{FS}	V_{DS}=5V,I_D=20A	35	-	-	S
Diode Characteristics						
Diode Forward Voltage	V_{SD}	I_{SD}=10A,V_{GS}=0V	-	0.82	1.2	V
Diode Continuous Forward Current	I_S		-	-	16	A
Reverse Recovery Time	t_{rr}	T_J = 25°C, I_F = I_S di/dt = 100A/μs	-	40	-	ns
Reverse Recovery Charge	Q_{rr}		-	50	-	nC
Dynamic Characteristics						
Gate Resistance	R_G	V_{GS}=0V, V_{DS}=0V,f=1MHz	-	1.2	1.8	Ω
Input capacitance	C_{ISS}	V_{GS}=0V ,V_{DS}=30V f=1.0MHz	-	4000	-	pF
Output capacitance	C_{OSS}		-	680	-	
Reverse transfer capacitance	C_{RSS}		-	23	-	
Turn-on delay time	$t_{D(ON)}$	V_{GS}=10V, V_{DS}=30V, R_L=1.7Ω, R_G=3Ω	-	11	-	ns
Turn-on Rise time	tr		-	5	-	
Turn-off delay time	$t_{D(OFF)}$		-	56	-	
Turn-off Fall time	t_f		-	12	-	
Total gate charge	Q_g	V_{GS}=10V, V_{DS}=30V， I_D=20A	-	67	-	nC
Gate-source charge	Q_{gs}		-	12	-	
Gate-drain charge	Q_{gd}		5	8.5	-	

Thermal Characteristics

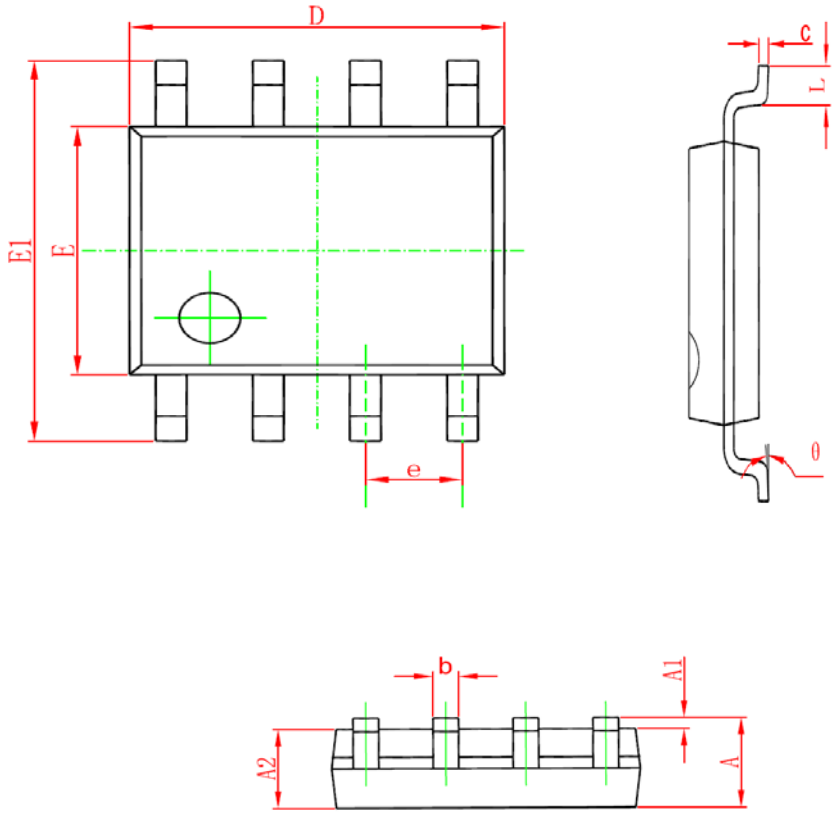
Parameter		Symbol	Typ	Max	Unit
Maximum Junction-to-Ambient[A]	≤ 10s	$R_{θJA}$	33	40	℃/W
Maximum Junction-to-Ambient[A]	Steady-State		59	75	
Maximum Junction-to-Lead[B]	Steady-State	$R_{θJC}$	16	24	

A:The value of R qJA is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with T A=25°C. The value in any given application depends on the user's specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.

B: The R qJA is the sum of the thermal impedence from junction to lead R qJL and lead to ambient.

Package Information

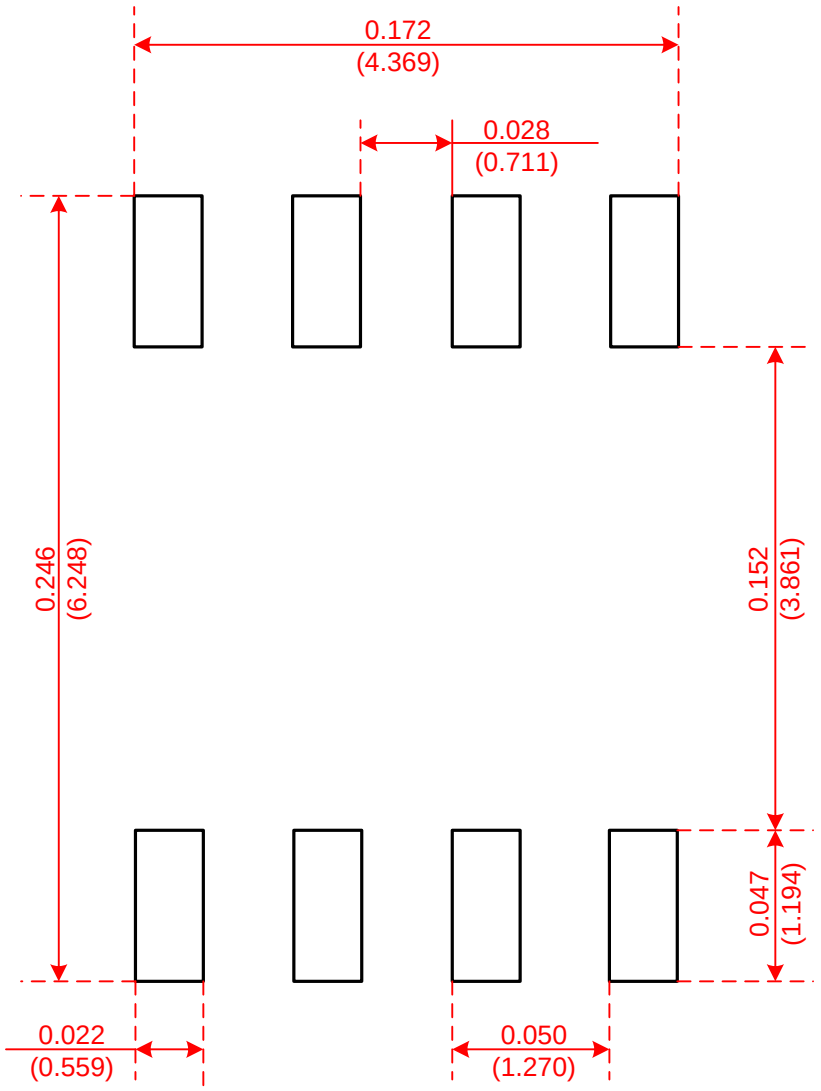
- **SOP-8**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Recommended Minimum Pads

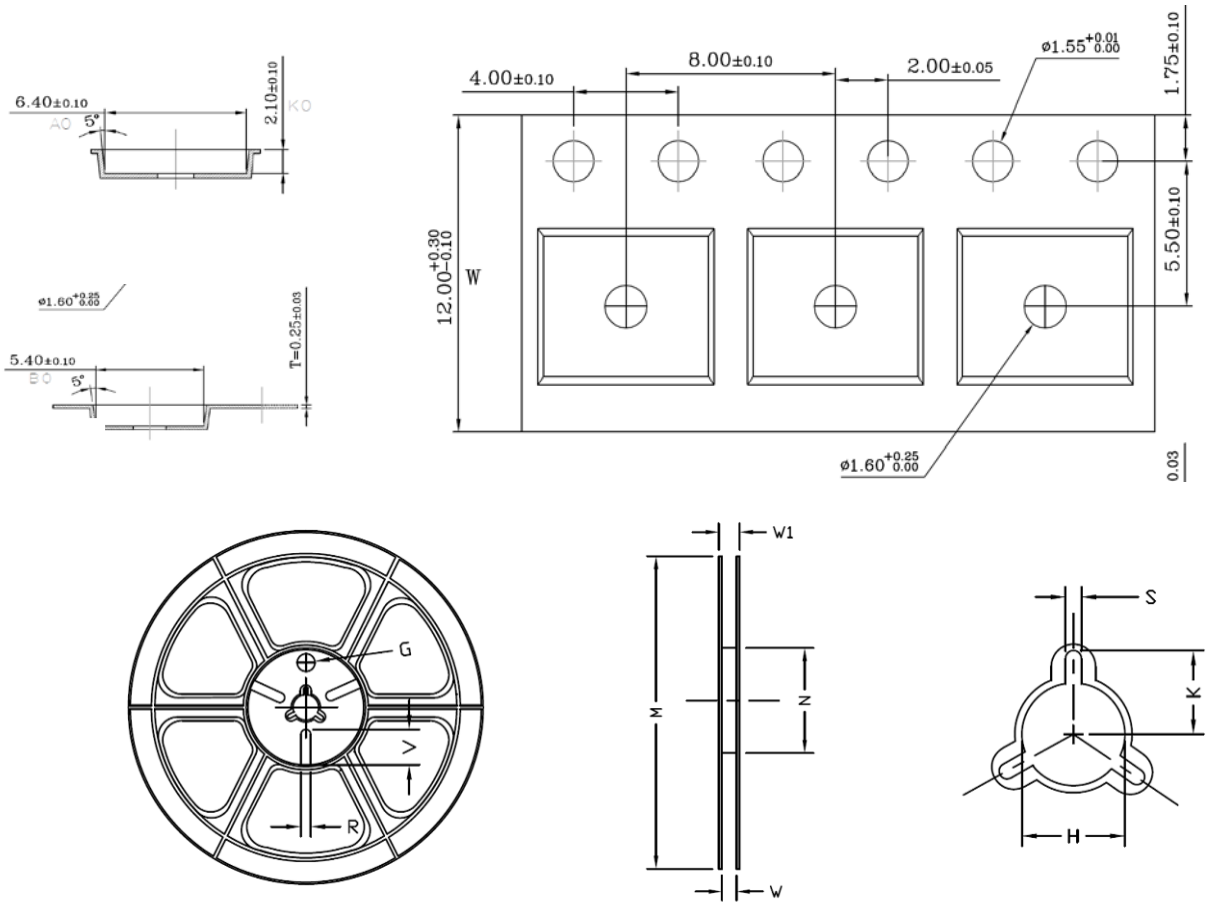
- **SOP-8**



Recommended Minimum Pads
Dimensions in Inches/(mm)

Tape and Reel

- **SOP-8**



Tape Size	Reel Size	M	N	W	W1	H	K	S	G	R	V
12mm	Φ330	Φ330.00 ±0.50	Φ97.00 ±0.30	13.00 ±0.30	17.40 ±1.00	Φ13.00 ±0.5	10.6	2.00 ±0.50	—	—	—

Unit Per Reel:
4000pcs